OPB703 through OPB705, OPB703WZ through OPB705WZ, OPB70AWZ through OPB70HWZ

Features:

- Phototransistor output
- High sensitivity
- Low-cost plastic housing
- Available with lenses for dust protection and ambient light filtration
- Focused for maximum sensitivity



Description:

The **OPB703**, **OPB704** and **OPB705** consist of an Infrared (890nm) Light Emitting Diode (LED) and a NPN silicon Phototransistor, mounted side-by-side on converging optical axes in a black plastic housing and are designed for PCBoard mounting. The **OPB703WZ**, **OPB704WZ**, **OPB705WZ** and **OPB70BWZ** are designed for remote mounting utilizing interconnect wires of UL approved 26 AWG, 24" (61.0cm) minimum length, stripped and tinned.

The **OPB70AWZ** consists of an Infrared (890nm) Light Emitting Diode (LED) and a NPN silicon Photodarlington, mounted side-by-side on converging optical axes in a black plastic housing and is designed for remote mounting utilizing interconnect wires of UL approved 26 AWG, 24" (61.0cm) minimum length, stripped and tinned.

The **OPB70CWZ through OPB70FWZ** consist of a Visible (Red 640nm) Light Emitting Diode (LED) and a NPN silicon Phototransistor or Rbe Phototransistor, mounted side-by-side on converging optical axes in a black plastic housing and are designed for remote mounting utilizing interconnect wires of UL approved 26 AWG, 24" (61.0cm) minimum length, stripped and tinned.

Various lens options are available: No lens for the (OPB703, OPB703WZ), blue window for dust protection for the (OPB704, OPB704WZ, OPB70BWZ, OPB70HWZ) and aperture lens for improved resolution for the (OPB705, OPB705WZ, OPB705WZ, OPB70DWZ). The OPB704G and OPB704GWZ offers excellent protection for dirty environments.

The phototransistor responds to illumination from the emitter when a reflective object passes within the field of view centered typically at 0.15" (3.8 mm).

Custom electrical, wire, cabling and connectors are available. Contact your local representative or OPTEK for more information.

Applications:

- Non-contact reflective object sensor
- Assembly line automation
- Machine automation
- Machine safety
- End of travel sensor
- Door sensor
- Mark Detection
- Office Equipment

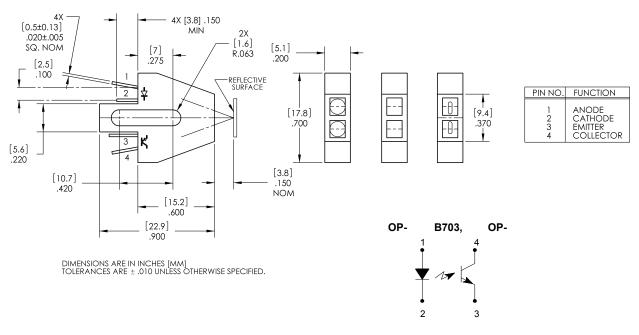
Ordering Information									
Part	LED Peak	Detector	Optical Cover	Lead or Wire					
OPB703			None	0.160" Leads					
OPB703WZ			None	24" / 26 AWG Wire					
OPB704				0.160" Leads					
OPB704WZ				24" / 26 AWG Wire					
OPB70HWZ		Transistor	Blue Window	24" / 26 AWG Wire					
OPB704G	890 nm			0.160" Leads					
OPB704GWZ				24" / 26 AWG Wire					
OPB705				0.160" Leads					
OPB705WZ			Aperture						
OPB70AWZ		Darlington							
OPB70BWZ		Rbe Transistor	Blue Window						
OPB70CWZ		Rbe Transistor	A	24" / 26 AWG Wire					
OPB70DWZ	640	Transistor	Aperture						
OPB70EWZ	640 nm	Rbe Transistor	Class NA/in da						
OPB70FWZ		Transistor	Clear Window						



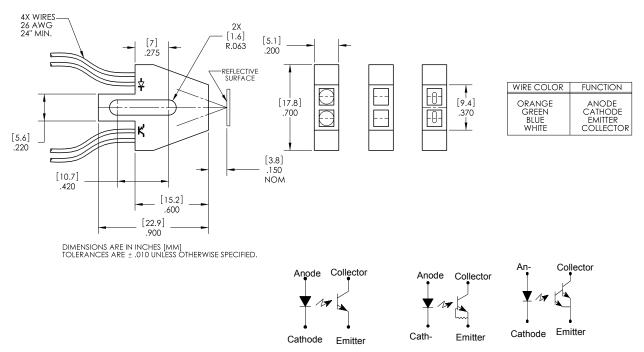
OPB703 through OPB705, OPB703WZ through OPB705WZ, OPB70AWZ through OPB70HWZ



OPB703, OPB704, OPB705



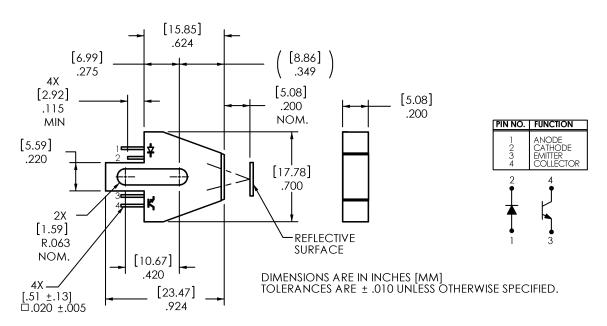
OPB703WZ, OPB704WZ, OPB705WZ, OPB70AWZ, OPB70BWZ, OPB70CWZ, OPB70DWZ



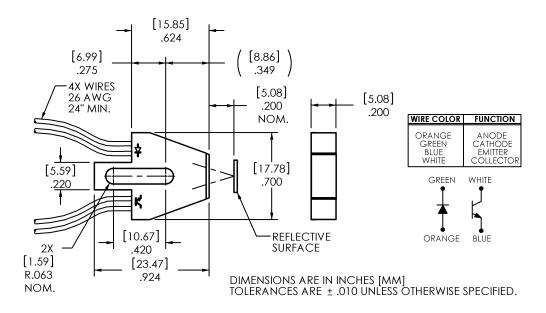
OPB703 through OPB705, OPB703WZ through OPB705WZ, OPB70AWZ through OPB70HWZ



OPB704G



OPB704GWZ



OPB703 through OPB705, OPB703WZ through OPB705WZ, OPB70AWZ through OPB70HWZ



Absolute Maximum Ratings (T _A =25°C unless otherwise noted)						
Storage Temperature Range	-40°C to +80° C					
Lead Soldering Temperature [1/16 inch (1.6 mm) from the case for 5 sec. with soldering iron]	240° C ⁽¹⁾					
Input Diode						
Forward DC Current	40 mA					
Reverse DC Voltage	2 V					
Power Dissipation	100 mW ⁽²⁾					
Output Photodetector						
Collector-Emitter Voltage Phototransistor Photodarlington	30 V 15 V					
Emitter-Collector Voltage	5 V					
Collector DC Current	25 mA					
Power Dissipation	100 mW ⁽²⁾					

Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) For OPB703WZ, OPB704WZ, OPB705WZ, OPB70BWZ, OPB704G, OPB704GWZ and OPB70HWZ derate linearly 1.82 mW/° C above 25° C.

OPB703 through OPB705, OPB703WZ through OPB705WZ, OPB70AWZ through OPB70HWZ



Electrical Characteristics (T_A = 25° C unless otherwise noted)
(OPB703, OPB703WZ, OPB704, OPB704WZ, OPB705, OPB705WZ, OPB704G, OPB704GWZ, OPB70HWZ)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS		
Input Diode (See OP265 for additional information — for reference only)								
V_{F}	Forward Voltage	-	-	1.7	V	I _F = 40mA		
I _R	Reverse Current	-	-	100	μΑ	V _R = 2 V		
Output Phototransistor (See OP505 for additional information — for reference only)								
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	30	-	-	V	Ι _{CE} = 100 μΑ		
V _{(BR)ECO}	Emitter-Collector Breakdown Voltage	5	-	-	V	Ι _{ΕC} = 100μΑ		
I _{CEO}	Collector Dark Current	-	-	250	nA	$V_{CE} = 10 \text{ V, } I_F = 0, E_E = 0$		
Coupled								
I _{C(ON)}	On-State Collector Current OPB70HWZ OPB703, OPB703WZ OPB704, OPB704WZ	0.60 0.30 0.20	- - -	3.5 2.5 2.5	mA	$V_{CE} = 5 \text{ V, I}_F = 40 \text{mA}$, $d = 0.15''$ (4)(6)		
	OPB704G, OPB704GWZ	0.50	-	6.0		$V_{CE} = 5 \text{ V, } I_F = 40 \text{mA} \text{ , } d = 0.20'' \ ^{(4)(6)}$		
I _{CX}	Crosstalk OPB703, OPB703WZ OPB704, OPB704WZ, OPB70HWZ	-	-	20 20	μΑ	V _{CE} = 5 V, I _F = 40mA ⁽⁵⁾		

Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) For OPB703, OPB704 and OPB705, derate linearly 1.67 mW/° C above 25° C.
- (3) For OPB703WZ, OPB704WZ, OPB705WZ, OPB70BWZ, OPB704G, OPB704GWZ, OPB70HWZ, OPB70AWZ, OPB70CWZ, OPB70DWZ, OPB70EWZ, and OPB70FWZ derate linearly 1.82 mW/° C above 25° C.
- (4) The distance from the assembly face to the reflective surface is d.
- (5) Crosstalk (I_{CX}) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (6) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.
- (7) All parameters tested using pulse techniques.

OPB703 through OPB705, OPB703WZ through OPB705WZ, OPB70AWZ through OPB70HWZ



Electrical Characteristics (T _A = 25° C unless otherwise noted) (OPB70AWZ)									
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS			
Input Diode (See OP265 for additional information — for reference only)									
V _F	Forward Voltage	-	-	1.7	V	I _F = 40mA			
I _R	Reverse Current	-	-	100	μΑ	V _R = 2 V			
Output Ph	otoDarlington (See OP535 for additional i	informa	ntion —	for refe	erence or	nly)			
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	15	-	-	V	I _{CE} = 1.0 mA, E _E =0			
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	5	-	-	V	$I_{EC} = 100 \mu A, E_E = 0$			
I _{CEO}	Collector Dark Current	-	-	250	nA	$V_{CE} = 10 \text{ V}, I_F = 0, E_E = 0$			
Coupled		- -	-	- -	-				
I _{C(ON)}	On-State Collector Current	5.0	-	26.0	mA	V_{CE} = 5 V, I_F = 40mA , d = 0.15" $^{(1)(3)}$			
$V_{(SAT)}$	Saturation Voltage	-	-	1.15	V	$I_{\text{C}}\!=400~\mu\text{A},~I_{\text{F}}\!=40\text{mA}$, $d=0.15^{\prime\prime}~^{(1)(3)}$			
I _{CX}	Crosstalk	-	-	25	μΑ	$V_{CE} = 5 \text{ V, } I_F = 40 \text{mA}^{(2)}$			

Notes:

- (1) The distance from the assembly face to the reflective surface is d.
- (2) Crosstalk (I_{CX}) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (3) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.

OPB703 through OPB705, OPB703WZ through OPB705WZ, OPB70AWZ through OPB70HWZ



Electrical Characteristics (T _A = 25° C unless otherwise noted) (OPB70BWZ)									
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS			
Input Diod	Input Diode (See OP265 for additional information — for reference only)								
V_{F}	Forward Voltage	-	-	1.7	V	I _F = 40mA			
I _R	Reverse Current	-	-	100	μΑ	V _R = 2 V			
Output Ph	Output Phototransistor (See OP705 for additional information — for reference only)								
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	30	-	-	V	Ι _{CE} = 100 μΑ			
V _{(BR)ECO}	Emitter-Collector Breakdown Voltage	0.4	-	-	V	$I_{EC} = 100 \mu A$			
I _{CEO}	Collector Dark Current	-	-	100	nA	$V_{CE} = 10 \text{ V}, I_F = 0, E_E = 0$			
Coupled	Coupled								
I _{C(ON)}	On-State Collector Current OPB70BWZ	0.50	-	3.0	mA	$V_{CE} = 5 \text{ V, I}_F = 40 \text{mA} \text{ , d} = 0.15'' \ ^{(1)(3)}$			
I _{CX}	Crosstalk OPB70BWZ	-	-	5	μА	$V_{CE} = 5 \text{ V, } I_F = 40 \text{mA}^{(2)}$			

Notes:

- (1) The distance from the assembly face to the reflective surface is d.
- (2) Crosstalk (I_{CX}) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (3) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.

OPB703 through OPB705, OPB703WZ through OPB705WZ, OPB70AWZ through OPB70HWZ

Reverse Current



 $V_R = 2 V$

Electrical Characteristics (T _A = 25° C unless otherwise noted) (OPB70CWZ and OPB70EWZ)									
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS			
Input Diode (See OVLAS6CB8 for additional information — for reference only)									
V_{F}	Forward Voltage	-	-	2.6	V	I _F = 40mA			

Output Phototransistor (See OP505 for additional information — for reference only)								
V _{(BR)CEO}	$V_{(BR)CEO}$ Collector-Emitter Breakdown Voltage 30 V $I_{CE} = 100 \mu A$, $I_F = 0$, $E_E = 0$							
V _{(BR)ECO}	Emitter-Collector Breakdown Voltage	0.4	-	-	V	$I_{EC} = 100 \mu A, I_F = 0, E_E = 0$		
I _{CEO}	Collector Dark Current	-	-	100	nA	$V_{CE} = 10 \text{ V}, I_F = 0, E_E = 0$		

100

μΑ

Coupled

 I_R

	On-State Collector Cur-	OPB70CWZ	.10	-	1.0	mA	$V_{CE} = 5 \text{ V, } I_F = 40 \text{mA} \text{ , } d = 0.15'' ^{(21(3))}$
I _C (ON)	rent	OPB70EWZ	.25	-	2.5	IIIA	
V _(SAT)	Saturation Voltage		-	-	0.4	V	I_{C} = 100 $\mu\text{A},~I_{F}$ = 40mA , d = 0.15" $^{(1)(3)}$
I _{CX}	Crosstalk		-	-	2	μΑ	$V_{CE} = 5 \text{ V, } I_F = 40 \text{mA}^{(2)}$

Notes:

- (1) The distance from the assembly face to the reflective surface is d.
- (2) Crosstalk (I_{Cx}) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (3) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.

OPB703 through OPB705, OPB703WZ through OPB705WZ, OPB70AWZ through OPB70HWZ



 $V_{CE} = 10 \text{ V}, I_F = 0, E_E = 0$

Electrical Characteristics (T _A = 25° C unless otherwise noted) (OPB70DWZ and OPB70FWZ)									
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS			
Input Diod	Input Diode (See OVLAS6CB8 for additional information — for reference only)								
V _F	Forward Voltage	-	-	2.6	V	I _F = 40mA			
I _R	Reverse Current	-	-	100	μΑ	V _R = 2 V			
Output Phototransistor (See OP505 for additional information — for reference only)									
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	30	-	-	V	$I_{CE} = 100 \mu A$, $I_F = 0$, $E_E = 0$			
V _{(BR)ECO}	Emitter-Collector Breakdown Voltage	5.0	-	-	V	$I_{EC} = 100 \mu A$, $I_F = 0$, $E_E = 0$			

Coupled									
	I _{C(ON)} On-State Collector Current	OPB70DWZ	.10	-	1.5	т Л	$V_{CE} = 5 \text{ V, I}_F = 40 \text{mA} \text{ , d} = 0.15'' ^{(1)(3)}$		
IC(ON)		OPB70FWZ	.25	-	3.5	mA			
V _(SAT)	Saturation Voltage		-	-	0.4	V	$I_{C(ON)}\!=100~\mu\text{A},~I_F\!=40\text{mA}$, d = 0.15" $^{(1)(3)}$		
I _{CX}	Crosstalk		-	-	5.0	μΑ	$V_{CE} = 5 \text{ V, } I_F = 40 \text{mA}^{(2)}$		

250

Notes:

 I_{CEO}

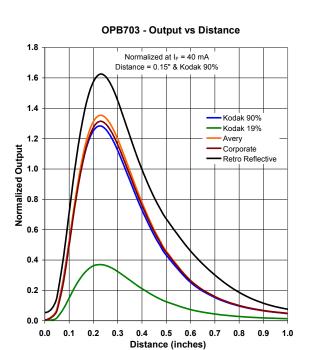
(1) The distance from the assembly face to the reflective surface is d.

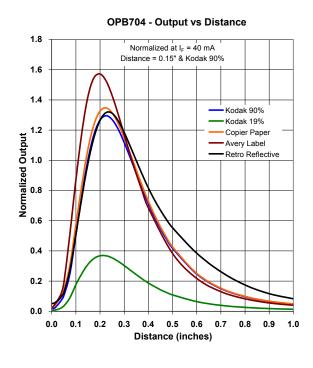
Collector Dark Current

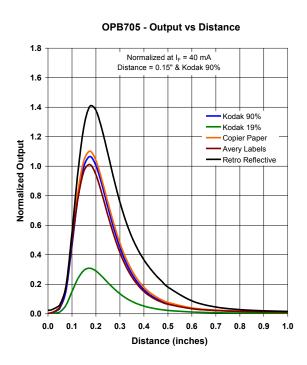
- (2) Crosstalk (I_{CX}) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (3) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.

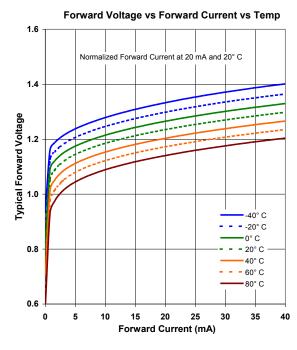
OPB703 through OPB705, OPB703WZ through OPB705WZ, OPB70AWZ through OPB70HWZ











General Note TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

OPB703 through OPB705, OPB703WZ through OPB705WZ, OPB70AWZ through OPB70HWZ



